

Critical microwave-conductivity fluctuations across the phase diagram of superconducting $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ thin films

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We report a systematic study of the dynamic microwave conductivity near T_c for $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ (LSCO) thin films with $x=0.07$ to 0.16 . The strong frequency dependence of the phase stiffness together with scaling analysis of the ac fluctuating conductivity of superconductivity provide direct evidence for the 2D-XY behavior of nearly decoupled CuO_2 planes in underdoped LSCO ($x=0.07$ and 0.12). On the other hand, the critical exponents for slightly overdoped LSCO ($x=0.16$) were found to agree with those for the relaxational 3D-XY model, indicating that the universality class in LSCO is changed by hole doping. The implication of these results for the phase diagram of high- T_c cuprates is discussed.

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One of the hallmarks of the high- T_c cuprates is the large thermal fluctuation of the superconducting order enhanced by the short coherence length and the quasi two-dimensionality, which enables the exploration of the fluctuation-dominated critical regime very close to T_c ¹. Although numerous measurements, such as the ac conductivity², the dc magnetization³, the specific heat⁴, and the I-V curves⁵, have been performed to investigate the critical fluctuation, there has been no consensus among the results. This is surprising because the critical phenomena were considered to be universal, independent of the microscopic details⁶. However, if many assumptions were made implicitly to determine the universality class of the phase transition from the data, the obtained results are not convincing unless the validity of such assumptions is confirmed. Thus, one should develop a more reliable method which does not require any extra assumptions. To our knowledge, the most successful method is dynamic scaling analysis of the ac complex conductivity, $\sigma(\omega) = \sigma_1(\omega) - i\sigma_2(\omega)$, as will be discussed later.

Another fascinating hallmark of the high- T_c cuprates is that the physical properties change with hole doping. In particular, an understanding of the phase diagram as a plot of T_c versus the hole concentration has been a central issue in the physics of high- T_c cuprates. Interestingly, some recent models, which start from the quantum criticality for competing orders underlying the phase diagram of high- T_c cuprates, provide another possible explanation for the critical fluctuations in high- T_c cuprates. That is, the critical fluctuations change with hole doping, because of the existence of a quantum critical point (QCP)⁷. These models suggest that the critical dynamics should be investigated as a function of hole doping. Thus, it can be expected that such a systematic study across the phase diagram will not only resolve the disagreements among earlier studies but will also provide important information to understand the phase diagram of high- T_c cuprates.

In this paper, we report a systematic study of $\sigma(\omega)$ as a function of the swept-frequency (0.1 GHz to 12 GHz) for high-quality $\text{La}_{2-x}\text{Sr}_x\text{CuO}_4$ (LSCO) thin films with a wide range of hole concentrations ($x=0.07$ to 0.16). For underdoped (UD) LSCO, we show clear evidence for the 2D-XY critical fluctuation of nearly decoupled CuO_2 planes. With increasing hole doping, a dimensional crossover from 2D-XY behavior to 3D-XY behavior was observed near $x=0.16$, implying that there are at least two universality classes in the phase diagram of LSCO.

Epitaxial LSCO thin films with $x=0.07$, 0.12 (underdoped), 0.14 (nearly optimally doped), and 0.16 (overdoped) were grown on LaSrAlO_4 (001) substrates by a pulsed laser deposition technique using pure ozone⁸. All the films are highly c-axis oriented with a sufficiently narrow rocking curve of the 002 reflection (typically 0.2°). As shown in Table I, the value of the in-plane dc resistivity, ρ_{dc} , was found to agree with the reported best value for LSCO thin films⁹ within a factor of 2, confirming that the films used in this study are of sufficiently high quality to investigate the critical dynamics near T_c .

There are three reasons for using LSCO films on LaSrAlO_4 (LSAO) substrates in this study: (1) LSCO is an ideal system with a simple layered structure, where the hole concentration can be widely controlled. (2) The compressive epitaxial strain gives rise to a moderate increase of T_c ⁹. (3) The tetragonal symmetry of LSAO

TABLE I: Values of t , ρ_{dc} , and T_c for the measured films. ρ_{dc} is the value at $T = 50$ K. As for three kinds of T_c , see the text for definition.

x	t (nm)	ρ_{dc} (m Ω cm)	T_c^{scale} (K)	T_c^0 (K)	T_{MF} (K)
0.07	460	0.77	19.0	20.83	32
0.12	230	0.28	33.65	36.08	38
0.14	270	0.14	38.92	39.29	40
0.16	140	0.12	35.5	35.82	

substrate supports the fabrication of CuO_2 planes with ideal at square lattices, free from disorders due to corrugations and twin boundaries⁸.

Both the real and imaginary parts of $\epsilon(\omega)$ were obtained from the complex reflection coefficient, $S_{11}(\omega)$, using a non-resonant broadband technique¹⁰. When the film thickness, t , is sufficiently less than the skin depth, δ , one can write $\epsilon(\omega)$, as follows,

$$\epsilon(\omega) = \frac{1}{Z_0} \frac{1}{1 + S_{11}(\omega)}; \quad (1)$$

where $Z_0 = 377 \Omega$ is the impedance of free space. In practice, before applying Eq. (1), systematic errors involved in $S_{11}(\omega)$ were carefully removed by calibration measurements using known standards¹⁰.

In order to obtain reliable $\epsilon(\omega)$ data, the effect of the dielectric substrate needs to be considered. Note that the choice of t according to values of δ_{dc} is important, because a resonance peak attributed to the effect of substrate can be induced for a very small value of t ¹¹. In fact, a sharp resonance peak has been observed near 8 GHz for the LSCO film ($x=0.07$) above 100 K¹⁰. However, in the data presented in Fig. 1, no peak was observed over the whole frequency range measured at lower temperatures near T_c . Thus, we can conclude that the effect of substrate was negligible near T_c .

Moreover, in the vicinity of T_c , we found that $\epsilon(\omega)$ was seriously affected by a small unexpected difference (typically, 0.2–0.3 at 1 GHz) between the phase of S_{11} for a load standard, $\backslash S_{11}^{\text{load}}$, and that for a short standard, $\backslash S_{11}^{\text{short}}$. This difficulty was resolved by using the measured $S_{11}(\omega)$ of the sample at a temperature far above T_c as the load standard, assuming that $\backslash S_{11}^{\text{short}} = \backslash S_{11}^{\text{load}}$

at this temperature, and that both were T -independent in the vicinity of T_c . The validity of this procedure was also confirmed by the same measurements for NbN thin films as a reference¹².

Figure 1 shows the frequency dependence of $\epsilon(\omega)$, obtained by the above procedures, for underdoped LSCO ($x=0.07$ and 0.12) at several temperatures above T_c . It is evident that both $\epsilon_1(\omega)$ and $\epsilon_2(\omega)$ diverge rapidly with decreasing temperature in the low frequency limit, suggesting that the excess conductivity is due to the superconducting fluctuations. A similar divergence in $\epsilon(\omega)$ was also observed in the vicinity of T_c for the other LSCO films.

It has been argued¹³ that strong phase fluctuations are important for the determination of T_c in the UD region, because the phase stiffness energy, $k_B T_c^0 \sim \frac{1}{2} \frac{e^2}{d_s} \sim \frac{1}{2} \frac{e^2}{d_s} \sim \frac{1}{2} \frac{e^2}{d_s}$, is suppressed largely by the small superfluid density, where d_s is the effective thickness of a superfluid. Figure 2 shows the phase stiffness temperature T_ϕ (T_ϕ) estimated from $\epsilon_2(\omega; T)$ at several frequencies. Surprisingly, we found that T_ϕ (T_ϕ) for the UD samples ($x=0.07$ and 0.12) started to show frequency dependence above a certain temperature, T_k , while T_ϕ (T_ϕ) was almost T -independent below T_k . In addition, the resistive T_c (T_c^R), where R became zero, was also close to T_k rather than another critical temperature, T_c^0 , where the bare phase stiffness in the XY model would go to zero. When we assumed d_s to be approximately $t=2$, we saw that a dashed straight line with a slope of 8 π crossed T_ϕ (T_ϕ) at T_k , indicating that T_k agrees with the Berezinskii-Kosterlitz-Thouless (BKT) transition temperature, T_{BKT} , in the 2D-XY model^{14,15}.

As shown in Figs. 2(c) and 2(d), this behavior was observed even for $x=0.14$, while it disappeared almost

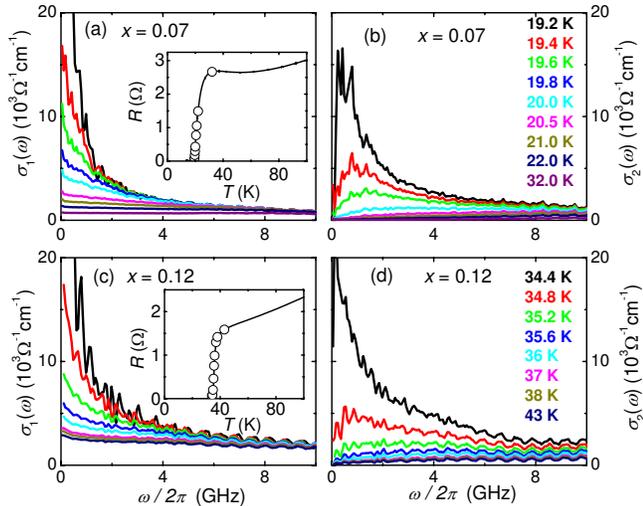


FIG. 1: The frequency dependence of (a) $\epsilon_1(\omega)$ for $x=0.07$, (b) $\epsilon_2(\omega)$ for $x=0.07$, (c) $\epsilon_1(\omega)$ for $x=0.12$, (d) $\epsilon_2(\omega)$ for $x=0.12$, respectively. Insets: the temperature dependence of the dc resistance, R , of the same sample. Open circles near T_c show R at the temperatures presented in the main panel.

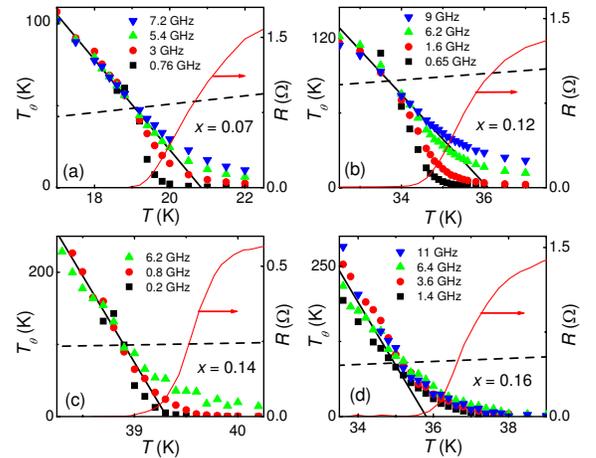


FIG. 2: The phase stiffness temperature for the film with (a) $x=0.07$, (b) $x=0.12$, (c) $x=0.14$, and (d) $x=0.16$. The dashed straight line represents $(8\pi)T$. The solid straight line gives the bare phase stiffness in the XY model, while it gives the mean-field superfluid density in the GL theory. In each panel, the dc resistance was given by red solid curves.

completely for $x = 0.16$. T_c^R for $x = 0.16$ was close to T_c^0 rather than T_{BKT} , suggesting that the mean field critical temperature T_{MF} is close to T_c^0 . Thus, our results were qualitatively similar to the prediction of Emery and Kivelson¹³ in the sense that T_c is bounded by T_{BKT} (UD region) or T_{MF} (overdoped region), although the estimation of T_{MF} in the UD region was considerably different, as will be discussed later.

In the dynamic scaling analysis of the fluctuating complex conductivity, $\sigma(\omega)$, which was pioneered by Booth et al.², both the magnitude, $|\sigma(\omega)|$, and the phase, $\arg[\sigma(\omega)]$, of $\sigma(\omega)$ are used as scaled quantities. The advantage of this method is that the data collapse to a single curve as a function of a reduced frequency, ω/ω_0 , can be achieved without assuming any relationship between two scaling parameters, ω_0 and ω_0' , in contrast to other scaling analyses^{3,4,5}. Note that ω_0 and ω_0' are obtained independently in our analysis. Thus, we can begin by checking the following hypothesis of the dynamic scaling theory¹,

$$|\sigma(\omega)| \sim \omega^{z+2d} S(\omega/\omega_0); \quad (2)$$

where $S(x)$ is a complex universal scaling function, ω_0 is a correlation length which diverges at T_c , z is a dynamic critical exponent, and d is an effective spatial dimension. Figure 3 shows that both $|\sigma(\omega)|$ and $\arg[\sigma(\omega)]$ were scaled successfully over a wide range of frequencies for all the

samples, confirming that the critical dynamics suggested by Eq. (2) were indeed observed. The comparison of the experimentally obtained scaling functions with the Gaussian forms calculated by Schmidt¹⁶ suggested that the 2D Gaussian-like behavior in the UD region changed into the 3D Gaussian-like behavior near $x = 0.16$.

Equation (2) suggests that both ω_0 and ω_0' behave as functions of $T - T_c$ in a critical region, where $\omega_0 \propto (T - T_c)^{-z+2d}$ and $\omega_0' \propto (T - T_c)^{-z}$. According to the BKT theory^{14,15}, $\omega_{K T}$ diverges with $\exp[b/(T - T_c)]$ in the critical region, $T_c < T < T_c^0$, where $T = T_c^{\text{scale}} + 1$ and b is a numerical constant. Note that $\omega_0 = 1/\omega_0'$ for the relaxational 2D system with $z = 2$ ¹. In fact, we confirmed that both ω_0 and ω_0' for $x = 0.07$ showed the same exponential singularity as $\omega_{K T}$ with $b = 0.215$ in the range of $T - T_c$ from 0.01 to 0.1, as shown in Figs. 4(a) and 4(b). With increasing x up to 0.14, we found that the range of $T - T_c$ where ω_0 (or ω_0') agreed with $\omega_{K T}$ became narrower and shifted to lower temperatures. Such behaviors were also consistent with the BKT theory¹⁵, since ω_0 (or ω_0') is rather dominated by free vortices than $\omega_{K T}$ at higher temperatures, due to a screening effect by thermally activated free vortices.

In the BKT theory, ω_0/ω_0' gives $T - T_c$ in the high-frequency limit, $T > T_c^0$, which is sensitive to the surviving bound pairs of vortices above T_{BKT} ¹⁵. As shown in Fig. 4(c), we found that ω_0/ω_0' decreased with increasing T more quickly at larger x . This suggests that the temperature region of the prominent phase fluctuation became narrower with hole doping, in contrast to a recent Nernst experiment¹⁷ which showed a steeper increase of the onset temperature of the Nernst effect than T_c with increasing hole doping. When

we roughly estimated T_{MF} , based on an expectation that $\omega_0/\omega_0' \rightarrow 0$ at T_{MF} , we found that T_{MF} was too small to cover the pseudogap region, as was previously reported by Corson et al.². These results strongly suggested that most of the anomalous Nernst signal should be attributed to other origins than the superconducting fluctuation, as was suggested by some recent theoretical works¹⁸.

Moreover, the observed reduction of T_c due to the phase fluctuation ($T_{BKT} = T_{MF} - 0.7, 0.9$ for $x = 0.07, 0.12$, respectively) corresponded to the superconducting \ln with a very high sheet resistance $R_{sq} \sim 3\text{--}5 \text{ k}\Omega$ ¹⁹. Using a relation $R_{sq} = \rho_{dc}/d_s$, we found that $d_s \sim 10 \text{ \AA}$. Thus, each of the CuO_2 planes seemed to be decoupled^{1,20}. Note that the screening length for each superconducting sheet, $\lambda_s (= \sqrt{2}d_s)$, where λ is a bulk penetration depth, was larger than 10 nm in this case, which satisfied the BKT criterion that $\lambda_s > L$, where L is the sample size. In addition, d_s is given by a sum of the decoupled superconducting layers with the thickness of d_s . Thus, d_s will be smaller than t , as we assumed in the estimation of $T_c(T)$ shown in Fig. 2.

We found that the critical behavior for $x = 0.16$ was very different from that for $x = 0.07\text{--}0.14$, as shown in Figs. 4(d) to 4(f). In particular, the dimensionality of $x = 0.16$ was found to be three, in contrast to the 2D-X Y behavior of $x = 0.07\text{--}0.14$, as shown by the plots of $\omega_0/\omega_0' \propto (T - T_c)^{-d}$ in Fig. 4(f), where d is a static critical exponent. We also confirmed that the critical exponents for $x = 0.16$ agreed very well with those for the relaxational 3D-X Y model with $\nu = 0.67$, $z = 2$, and $d = 3$ ¹. These results clearly suggest that the universality class in the phase diagram of LSCO changes from 2D-X Y to 3D-X Y with hole doping.

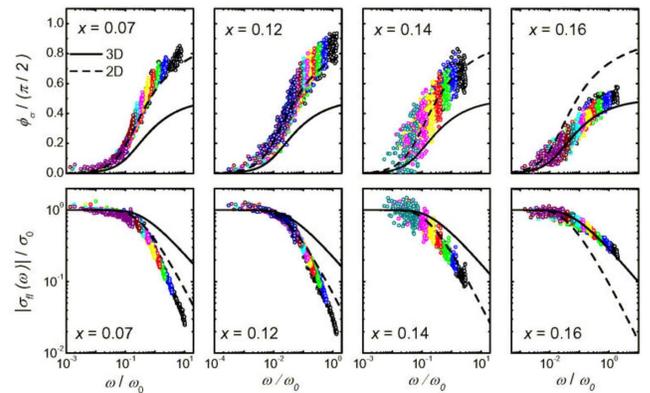


FIG. 3: Scaled curves of $\arg[\sigma(\omega)]$ (upper panels) and $|\sigma(\omega)|/\sigma_0$ (lower panels) for the measured LSCO \ln . $\sigma(\omega)$ was obtained by subtracting the normal-state conductivity at 32 K ($x = 0.07$), 38 K ($x = 0.12$) and 40 K ($x = 0.14, 0.16$), respectively. Data for $x = 0.07$ span the frequency range 0.2–7 GHz at reduced temperatures $T/T_c = 0.01\text{--}0.5$, while those for $x = 0.16$ span 0.2–2 GHz at reduced temperatures, $T/T_c = 0.002\text{--}0.08$. The solid (dashed) lines are the 3D (2D) Gaussian scaling functions.

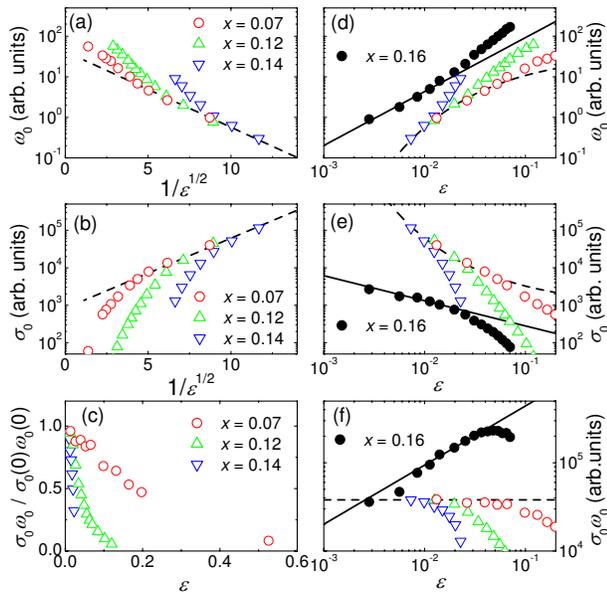


FIG. 4: (a) ρ_0 and (b) σ_0 as a function of $1/\epsilon^{1/2}$ for $x=0.07$ to 0.14, where $\epsilon = T/T_c^{\text{scale}} - 1$. The dashed line is (a) $\rho_0 \propto 1/\epsilon^{1/2}$ and (b) $\sigma_0 \propto 1/\epsilon^{1/2}$. (c) σ_0/ρ_0 vs ϵ for $x=0.07$ to 0.14. (d) ρ_0 , (e) σ_0 and (f) σ_0/ρ_0 as a function of ϵ for $x=0.07$ to 0.16. The solid line is (d) $\rho_0 \propto \epsilon^{1.33}$, (e) $\sigma_0 \propto \epsilon^{0.67}$ and (f) $\sigma_0/\rho_0 \propto \epsilon^{0.67}$. The dashed line is (d) $\rho_0 \propto \epsilon^{2/3}$, (e) $\sigma_0 \propto \epsilon^{2/3}$ and (f) the behavior expected in $d=2$. Note that the absolute values of the plots in all the panels except for (c) are unimportant, since they include arbitrary proportional coefficients.

What is the origin of the dimensional crossover from 2D-XY to 3D-XY? One of candidates is the increase of the interlayer coupling (probably Josephson coupling) with hole doping^{1,20}. However, this effect seems to ap-

pear more gradually with hole doping, in contrast to the different behavior between $x=0.14$ and 0.16 shown in Figs. 3 and 4(f). Another candidate is the effect of the quantum critical fluctuation near QCP. In this case, the 2D-3D crossover can be regarded as the classical-to-quantum crossover near QCP⁷. A detailed study for further overdoped LSCO is needed to settle this issue.

Finally, we emphasize that all the above results rule out the possibility of the distribution of T_c due to disorders in the sample. If there is a broad distribution of T_c in the sample, ρ_0 will be greatly suppressed, leading to a smaller T , and the dynamic scaling of j and ω will fail below a certain temperature, suggesting that T_c^{scale} is higher than T_c^R . In fact, these features have been observed for NbN thin film with a non-negligible distribution of T_c ¹², while all of the four LSCO thin films used for this study did not show them, as shown in Figs. 2 to 4.

In conclusion, a systematic study of the critical dynamics of (!) for LSCO thin film with $x=0.07$ to 0.16 has been performed for the first time. All the results clearly provide evidence for the BKT transition in the nearly decoupled CuO_2 layers of underdoped LSCO. With increasing hole doping, the 2D-XY behavior in the UD region changes into the 3D-XY behavior near $x=0.16$, indicating that the universality class in the phase diagram of LSCO is changed by hole doping.

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